# 2SA2009

## Silicon PNP epitaxial planar type

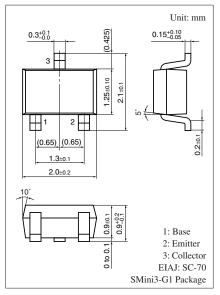
For low-frequency high breakdown voltage amplification

### ■ Features

- $\bullet$  High collector-emitter voltage (Base open)  $V_{\text{CEO}}$
- Low noise voltage NV
- S-Mini type package, allowing downsizing and thinning of the equipment and automatic insertion through the tape packing.

### ■ Absolute Maximum Ratings $T_a = 25$ °C

| Parameter                             | Symbol           | Rating      | Unit |
|---------------------------------------|------------------|-------------|------|
| Collector-base voltage (Emitter open) | V <sub>CBO</sub> | -120        | V    |
| Collector-emitter voltage (Base open) | V <sub>CEO</sub> | -120        | V    |
| Emitter-base voltage (Collector open) | $V_{EBO}$        | -5          | V    |
| Collector current                     | $I_C$            | -20         | mA   |
| Peak collector current                | $I_{CP}$         | -50         | mA   |
| Collector power dissipation           | P <sub>C</sub>   | 150         | mW   |
| Junction temperature                  | $T_j$            | 150         | °C   |
| Storage temperature                   | T <sub>stg</sub> | -55 to +150 | °C   |



Marking Symbol: AR

## $\blacksquare$ Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

| Parameter                                    | Symbol               | Conditions   | Min  | Тур | Max   | Unit |
|--|----------------------|--|------|-----|-------|------|
| Collector-base voltage (Emitter open)        | V <sub>CBO</sub>     | $I_C = -10 \ \mu A, I_E = 0$   | -120 |     |       | V    |
| Collector-emitter voltage (Base open)        | V <sub>CEO</sub>     | $I_C = -1 \text{ mA}, I_B = 0$   | -120 |     |       | V    |
| Emitter-base voltage (Collector open)        | $V_{EBO}$            | $I_E = -10 \mu A, I_C = 0$   | -5   |     |       | V    |
| Collector-base cutoff current (Emitter open) | $I_{CBO}$            | $V_{CB} = -50 \text{ V}, I_{E} = 0$                                    |      |     | -100  | nA   |
| Collector-emitter cutoff current (Base open) | $I_{CEO}$            | $V_{CE} = -50 \text{ V}, I_B = 0$                                      |      |     | -1    | μΑ   |
| Forward current transfer ratio *             | $h_{FE}$             | $V_{CE} = -5 \text{ V}, I_{C} = -2 \text{ mA}$                         | 180  |     | 700   | _    |
| Collector-emitter saturation voltage         | V <sub>CE(sat)</sub> | $I_C = -20 \text{ mA}, I_B = -2 \text{ mA}$                            |      |     | - 0.6 | V    |
| Transition frequency                         | $f_T$                | $V_{CB} = -5 \text{ V}, I_E = 2 \text{ mA}, f = 200 \text{ MHz}$       |      | 200 |       | MHz  |
| Noise voltage                                | NV                   | $V_{CE} = -40 \text{ V}, I_{C} = -1 \text{ mA}, G_{V} = 80 \text{ dB}$ |      |     | 130   | mV   |
|  |                      | $R_g = 100 \text{ k}\Omega$ , Function = FLAT                          |      |     |       |      |

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

#### 2. \*: Rank classification

| Rank            | R          | S          | Т          |
|-----------------|------------|------------|------------|
| h <sub>FE</sub> | 180 to 360 | 260 to 520 | 360 to 700 |

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